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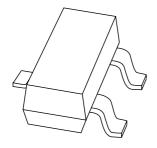
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



BFS19 NPN medium frequency transistor

Product data sheet Supersedes data of 1999 Apr 15 2004 Jan 05



NPN medium frequency transistor

BFS19

FEATURES

- I_{C(max)} = 25 mA
- V_{CEO(max)} = 20 V.

APPLICATIONS

Medium frequency applications in thick and thin-film circuits.

DESCRIPTION

NPN medium frequency transistor in a SOT23 plastic package.

MARKING

TYPE NUMBER	MARKING CODE(1)		
BFS19	F2*		

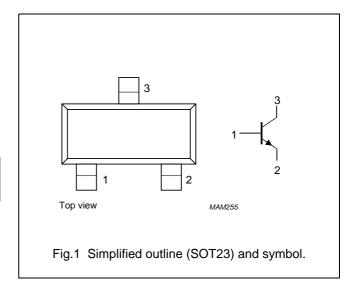
Note

* = p : Made in Hong Kong.
 * = t : Made in Malaysia.

* = W : Made in China.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



ORDERING INFORMATION

TYPE	PACKAGE				
NUMBER	NAME	DESCRIPTION VERSION			
BFS19	-	plastic surface mounted package; 3 leads	SOT23		

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NPN medium frequency transistor

BFS19

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	30	V
V_{CEO}	collector-emitter voltage	open base	_	20	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)		_	30	mA
I _{CM}	peak collector current		_	30	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

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NPN medium frequency transistor

BFS19

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 20 V	_	_	100	nA
		I _E = 0; V _{CB} = 20 V; T _j = 100 °C	_	_	10	μΑ
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V	_	_	100	nA
h _{FE}	DC current gain	I _C = 1 mA; V _{CE} = 10 V	65	_	225	
V_{BE}	base-emitter voltage	I _C = 1 mA; V _{CE} = 10 V	650	_	740	mV
C _c	collector capacitance	I _E = 0; V _{CB} = 10 V; f = 1 MHz	_	1	_	pF
C _{re}	feedback capacitance	I _C = 0 mA; V _{CB} = 10 V; f = 1 MHz	_	0.85	_	pF
f _T	transition frequency	I _C = 1 mA; V _{CE} = 10 V; f = 100 MHz	_	260	_	MHz

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NPN medium frequency transistor

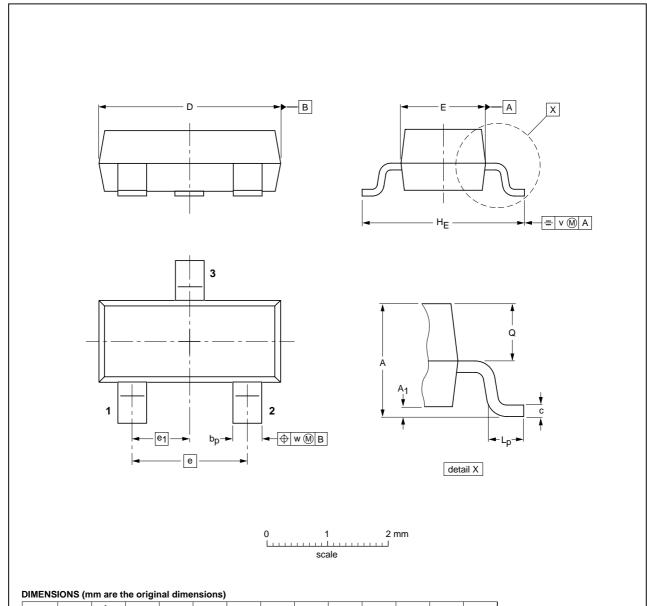
BFS19

PACKAGE OUTLINE

UNIT

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE	REFERENCES		EUROPEAN	ICCUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB				-04-11-04- 06-03-16

 $\mathbf{H}_{\mathbf{E}}$

 $\mathbf{L}_{\mathbf{p}}$

0.45

0.55

0.1

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bp

0.38

max

0.9

NPN medium frequency transistor

BFS19

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published
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